

■ ABSOLUTE MAXIMUM RATINGS

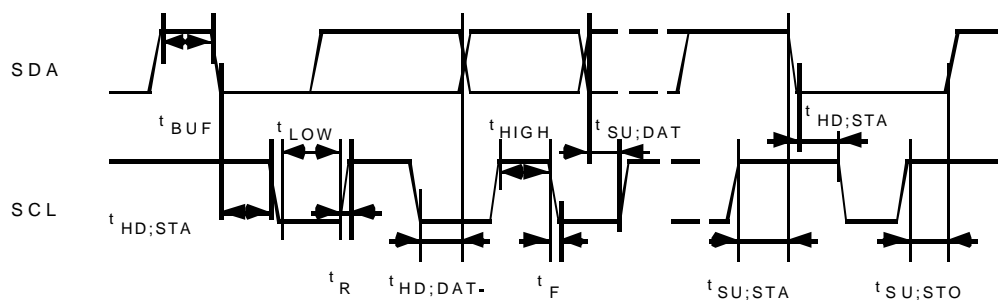
(T_A=25°C)

Parameter	Symbol	Ratings	Unit
Supply Voltage (Vcc1, 3)	Vcc1, Vcc3	-0.3 to +6.5	V
Supply Voltage (Vcc2)	Vcc2	-0.3 to +36	V
Input Voltage (except I ² C bus)	V _i	-0.3 to Vcc+0.3	V
Output Voltage (except I ² C bus)	V _o	-0.3 to Vcc+0.3	V
I ² C bus Input Voltage	V _{iiic}	-0.3 to 6.5	V
Power Dissipation	P _D	300	mW
Operating Temperature Range	T _{opr}	-20 to +85	°C
Storage Temperature Range	T _{stg}	-40 to +125	°C

■ RECOMMENDED OPERATING CONDITION

(T_A=25°C)

Parameter	Condition	Symbol	Min.	Typ.	Max.	Unit
Operating Voltage	Vcc1, Vcc3	Vcc1, Vcc3	4.5	5	5.5	V
Operating Voltage	Vcc2	Vcc2	0	-	34	V
X'tal Operating Range		f _{xial}	3.15	4	4.05	MHz
HF Input Frequency	Input= -20dBm	f _{hf}	80	-	1000	MHz
Clock Frequency		f _{SCL}	0	-	100	KHz
Bus Free Time		t _{BUF}	4.7	-	-	uS
Data Hold Time		t _{HDSTA}	2	-	-	uS
SCL Low Hold Time		t _{LOW}	4.7	-	-	uS
SCL High Hold Time		t _{HIGH}	2	-	-	uS
Set-up Time	Refer to I ² C bus Timing Chart	t _{SUSTA}	2	-	-	uS
Data Hold Time		t _{HDAT}	0	-	-	uS
Data Set-up Time		t _{SUDAT}	250	-	-	nS
Rise Time		t _R	-	-	1000	nS
Fall Time		t _F	-	-	300	nS
Data Set-up Time		t _{SUSTO}	4	-	-	uS



I²C bus Timing Chart

V_{IH}min(0.7 Vcc1) and V_{IL}max(0.3 Vcc1)

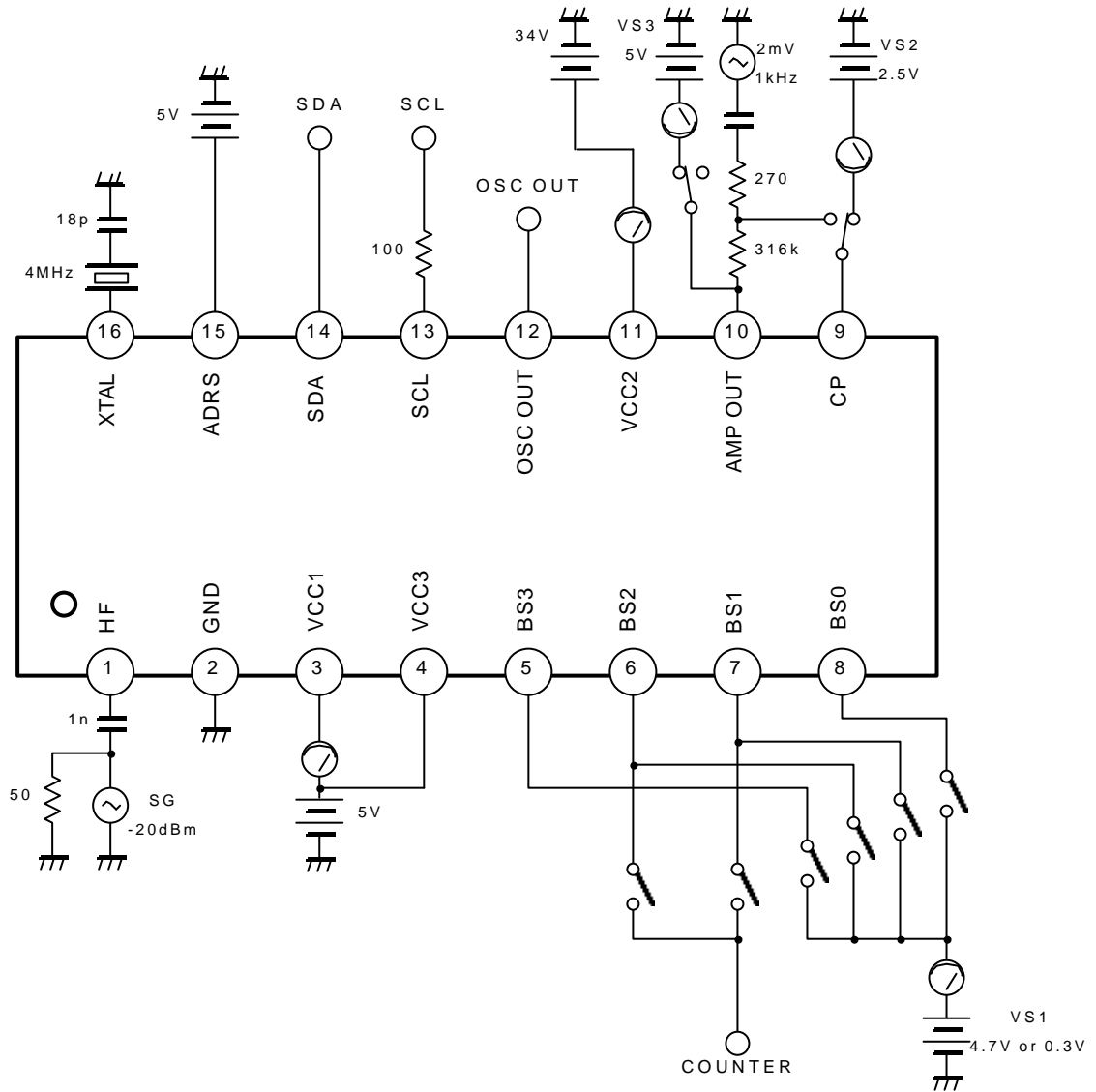
■ ELECTRICAL CHARACTERISTICS

(V_{cc1,3}=5V, V_{cc2}=34V, T_A=25°C)

Parameter	Condition	Symbol	Min.	Typ.	Max.	Unit
Operating Current 1	f _{HF} =100MHz	I _{CC}	12	15	21	mA
Operating Current 2	AMPOUT: Low Level	I _{CC2}	-	1.6	-	mA
AMP Input Current	Phase OUT: High Imp (2.5V)	I _{IN}	(-50)	0.1	(50)	nA
AMP Output Current	ANP OUT: Low Level AMPOUT Input=5V	I _{OUT}	-	-	-2	mA
AMP Gain	f=1KHz	AV	40	50	60	dB
Phase Comparator Output Current	Current Source	I _{source}	190	280	400	uA
Phase Comparator Output Current	Current Sink	I _{sink}	-400	-280	-190	uA
Band Switch						
"L" Output Current	BS0=BS1=0.3V	I _{OBS0-1L}	-2.0	-1	0	mA
"H" Output Current	BS0=BS1=4.7V	I _{OBS0-1H}	11.0	15.0	-	mA
"L" Output Current	BS2=BS3=0.3V	I _{OBS2-3L}	-2.0	-1.0	0	mA
"H" Output Current	BS2=BS3=4.7V	I _{OBS2-3H}	5.5	7.5	-	mA
I ² C bus						
"H" Input Current	SCL, SDA Terminal	I _{INH}	-5	0	5	uA
"L" Input Current	SCL, SDA Terminal	I _{INL}	-5	0	5	uA
"H" Input Voltage Range	SCL, SDA Terminal	V _{IH}	3.5	-	5.3	V
"L" Input Voltage Range	SCL, SDA Terminal	V _{IL}	0	-	1.5	V
ACK Sink Current	ACK Output, SDA=0.4V	V _{ACK}	3	-	-	mA

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■ TEST CIRCUIT



■ I²C bus Protocols

The input information, which consists of chip address and next two or four byte data, is received by I²C bus receiver. The allowable I²C bus protocols are as follows.

- (1) STA CA CB BB STO
- (2) STA CA D1 D2 STO
- (3) STA CA CB BB D1 D2 STO
- (4) STA CA D1 D2 CB BB STO

STA: Start Condition

STO: Stop Condition

CA: Chip Address

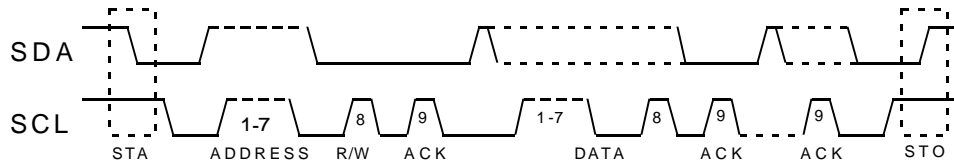
CB: Control Byte

BB: Band switch Byte

D1: Divider Byte 1

D2: Divider Byte 2

For suitable circuit operation, 5-byte data should have chip address, 2-byte control data, band data, and 2-byte divider byte. Following chip address, 2-byte data is received. For distinction of each data, first and third data byte has a function bit. As function bit, divider byte has "1" and control/band data has "0".



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■ Data Format

Parameter	Symbol	MSB								LSB
Chip Address	CA	1	1	0	0	0	CA1	CA0	0	A
Divider Byte 1	D1	0	N14	N13	N12	N11	N10	N9	N8	A
Divider Byte 2	D2	N7	N6	N5	N4	N3	N2	N1	N0	A
Control Byte	CB	1	CP	T2	T1	T0	RD1	RD0	x	A
Band switch Byte	BB	x	x	x	x	BS3	BS2	BS1	BS0	A

· Data specifications

x : don't care ;0 or 1

CA1, CA0 : Programmable address bits

ADRS Voltage	CA1	CA0
Always valid	0	1
0 to 0.1 Vcc1	0	0
0.4 Vcc1 to 0.6 Vcc1	1	0
0.9 Vcc1 to Vcc1	1	1

BS0 to BS3 : Band switch buffers Control bits, BS_n=1 then "ON"

N0 to N14 : Control of Programmable divider bits, N14=MSB N0=LSB

Dividing ratio : $N=2^{14} \times N14 + 2^{13} \times N13 + \dots + 2^1 \times N1 + N0$

Maximum division ratio 32767

Minimum division ratio 256

CP : Charge Pump Current

CP	Charge Pump Current	Conditions
1	280μA	Normal, Default
0	60μA	Test

T0 to T2 : Test mode bits

T0, T1, T2 : Phase Comparator Output bits

T2	T1	T0	Phase Comparator, Band Switch	Conditions
0	0	x	Normal Output	Normal, Default
1	0	1	Phase Comparator (High Impedance)	Test
1	1	0	Phase Comparator (Sink)	Test
1	1	1	Phase Comparator (Source)	Test

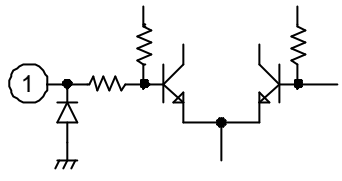
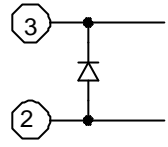
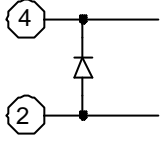
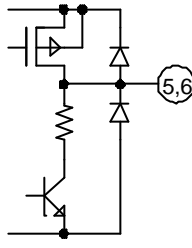
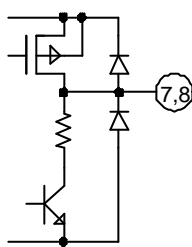
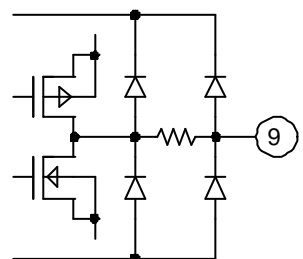
RD1, RD0 : Reference Divider bits

RD1	RD2	Reference Divider	Conditions
x	0	640	
1	1	512	Default
0	1	1024	

(Note)

Default : Power on reset

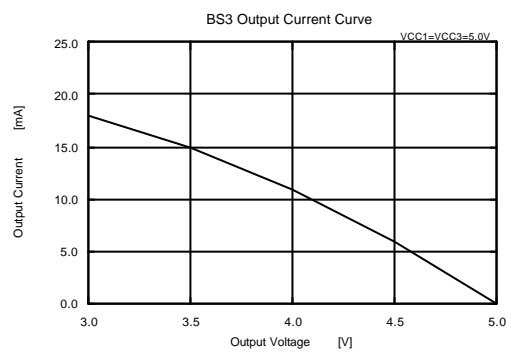
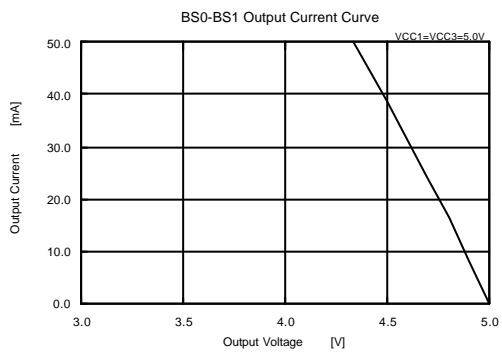
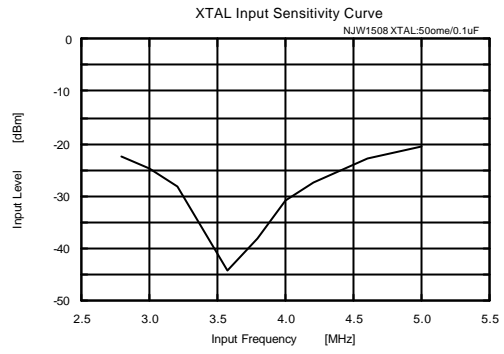
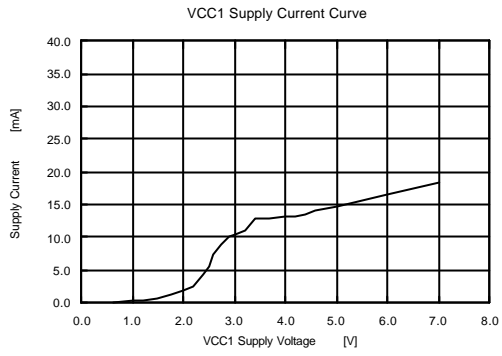
■ TERMINAL CHARACTERISTICS

No.	Symbol	Typ.DC Voltage (V)	Equivalent Circuit	Function
1	HF	3.2		High Frequency Signal Input
2	GND	0		GND
3	VCC1	5		Power Supply
4	VCC3	5		Band Switch Power Supply
5 6	BS3 BS2	0		Band Switch (Typ: 7.5mA)
7 8	BS1 BS0	0		Band Switch (Typ: 15mA)
9	CP	-		Charge Pump Output

No.	Symbol	Typ.DC Voltage (V)	Equivalent Circuit	Function
10	AMPOUT	-		Amplifier Output
11	VCC2	34		Amplifier Power Supply
12	OSCOUT	4.1		Reference Oscillator Output
13	SCL	-		SCL Input (I ² C bus)
14	SDA	-		SCL Input (I ² C bus)
15	ADRS	-		ADRS Input (I ² C bus)
16	XTAL	3.3		Crystal Input

■ TYPICAL CHARACTERISTICS

$T_A=25^\circ\text{C}$



MEMO

[CAUTION]

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